

TECHNICAL DATA
DATA SHEET 1082, REV. -

ULTRA LOW REVERSE LEAKAGE POWER SCHOTTKY RECTIFIER Very Low Voltage Drop

DESCRIPTION: A 100 VOLT, 60 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD5/5A/5B PACKAGE.

MAXIMUM RATINGS

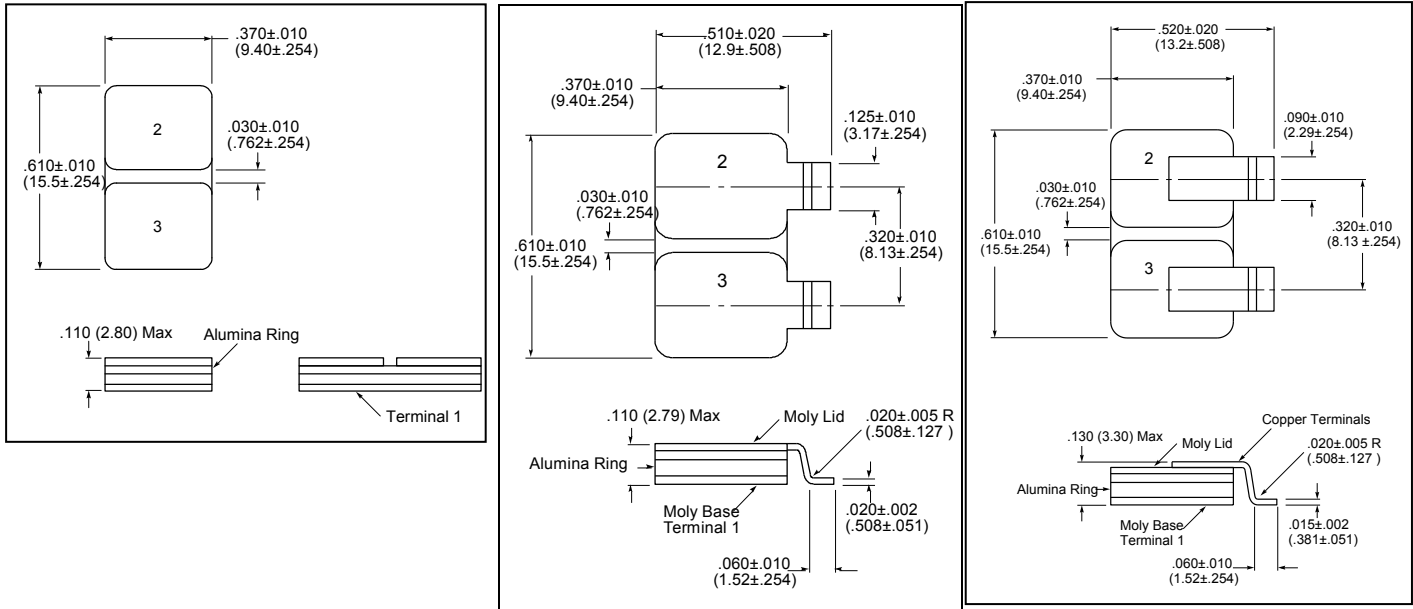
ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_O	60	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine Wave) (per leg)	I_{FSM}	570	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	1000	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	7.07	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top	-65 to + 175	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 30$ Amps) (per leg) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.84 0.68	Volts
MAXIMUM REVERSE CURRENT ($I_r @ 100\text{V PIV}$) (per leg) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.2 2.0	mA

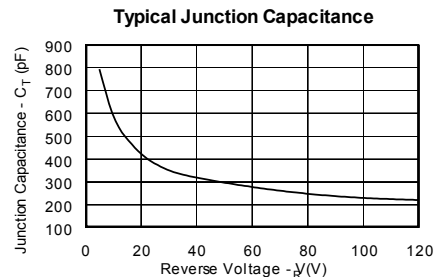
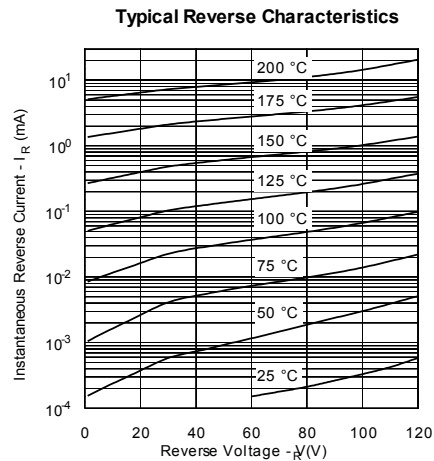
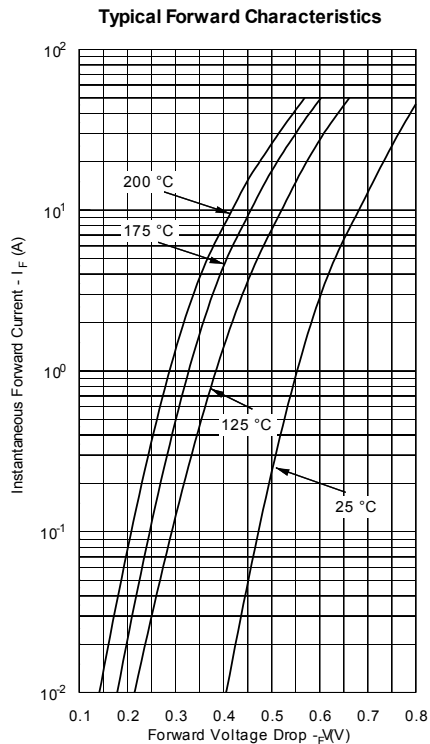
MECHANICAL DIMENSIONS: In Inches / mm



1 SHD-5B
COMMON CATHODE

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	COMMON CATHODE	ANODE	ANODE



SENSITRON

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